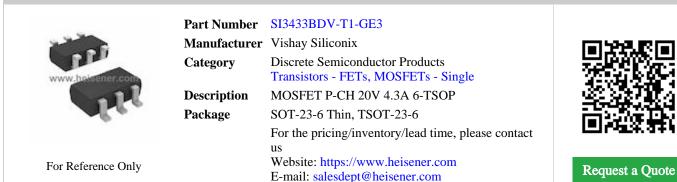


SI3433BDV-T1-GE3

SI3433BDV-T1-GE3 Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



SI3433BDV-T1-GE3 Specifications

Manufacturer Part Number	SI3433BDV-T1-GE3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	SOT-23-6 Thin, TSOT-23-6
Series	TrenchFET?
FET Type	P-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	20V
Current - Continuous Drain (Id) @ 25°C	4.3A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	1.8V, 4.5V
Vgs(th) (Max) @ Id	850mV @ 250µA
Gate Charge (Qg) (Max) @ Vgs	18nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	-
Vgs (Max)	$\pm 8\mathrm{V}$
FET Feature	-
Power Dissipation (Max)	1.1W (Ta)
Rds On (Max) @ Id, Vgs	42 mOhm @ 5.6A, 4.5V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	6-TSOP
Package / Case	SOT-23-6 Thin, TSOT-23-6
	Report errors?

SI3433BDV-T1-GE3 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

SI3433BDV-T1-GE3 Payment Methods





If you have any question about SI3433BDV-T1-GE3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com